

# High power PNP epitaxial planar bipolar transistor

#### **Features**

- High breakdown voltage V<sub>CEO</sub> = -140 V
- Complementary to 2STW4468
- Typical f<sub>t</sub> = 20 MHz
- Fully characterized at 125 °C

## **Applications**

Audio power amplifier

### **Description**

The device is a PNP transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour. Recommended for 70 W to 100 W high fidelity audio frequency amplifier output stage.

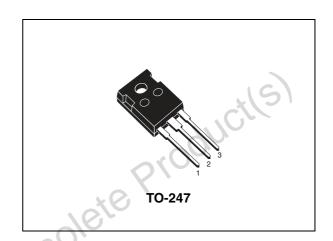


Figure 1. Internal schematic diagram

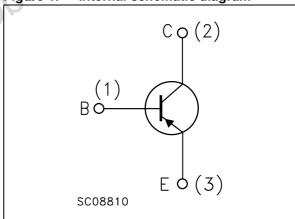


Table 1. Device summary

Order code	Marking	Package	Packaging
2STW1695	2STW1695	TO-247	Tube

**Electrical ratings** 2STW1695

#### **Electrical ratings** 1

Table 2. **Absolute maximum rating** 

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-base voltage (I <sub>E</sub> = 0)	-140	V
$V_{CEO}$	Collector-emitter voltage (I <sub>B</sub> = 0)	-140 V	
V <sub>EBO</sub>	Emitter-base voltage $(I_C = 0)$	-6	V
I <sub>C</sub> Collector current -10		-10	Α
I <sub>CM</sub> Collector peak current (t <sub>P</sub> < 5 ms)		-20	Α
P <sub>tot</sub>	P <sub>tot</sub> Total dissipation at T <sub>c</sub> = 25 °C 100		W
T <sub>stg</sub> Storage temperature		-65 to 150	°C
TJ	Max. operating junction temperature	150	°C
Table 3.	Thermal data	~,OQ,	O.
Symbol	Parameter	Value	Unit

Table 3. Thermal data

	Symbol	Parameter		Value	Unit
	R <sub>thj-case</sub>	Thermal resistance junction-case	max	1.25	°C/W
Obsole		"icile) Obs	max	1.25	°C/W
Obsole					

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#### **Electrical characteristics** 2

 $(T_{case} = 25 \, ^{\circ}C; \text{ unless otherwise specified})$ 

Table 4. **Electrical characteristics** 

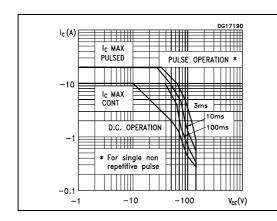
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = -140 V			-0.1	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = -6 V			-0.1	μΑ
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = -50 mA	-140		15	V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	I <sub>C</sub> = -100 μA	-140	$IO_C$		V
V <sub>(BR)EBO</sub> <sup>(1)</sup>		I <sub>E</sub> = -1 mA	-6	<i>J</i> .		V
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	$I_C = -5 \text{ A}$ $I_B = -500 \text{ mA}$ $I_C = -7 \text{ A}$ $I_B = -700 \text{ mA}$			-0.5 -0.7	V V
V <sub>BE</sub> <sup>(1)</sup>	Base-emitter voltage	$V_{CE} = -5 \text{ V}$ $I_{C} = -5 \text{ A}$			-1.3	V
h <sub>FE</sub>	DC current gain	$I_C = -3 \text{ A}$ $V_{CE} = -4 \text{ V}$ $I_C = -5 \text{ A}$ $V_{CE} = -4 \text{ V}$	70 50		140	
f <sub>T</sub>	Transition frequency	$I_C = -0.5 \text{ A}$ $V_{CE} = -12 \text{ V}$		20		MHz
C <sub>CBO</sub>	Collector-base capacitance $(I_E = 0)$	V <sub>CB</sub> = -10 V		225		pF
	Resistive load					
t <sub>on</sub>	Turn-on time	$I_C = -5 \text{ A}$ $V_{CC} = -60 \text{ V}$		0.24		μs
t <sub>stg</sub>	Storage time	$I_{B1} = -I_{B2} = -0.5 \text{ A}$		1.2		μs
t <sub>f</sub>	Fall time			0.24		μs
1. Pulsed: P	ulse duration = 300 µs, duty cycle	≤1.5 %				

Electrical characteristics 2STW1695

## 2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Output characteristics



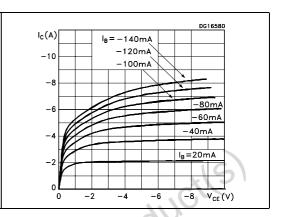
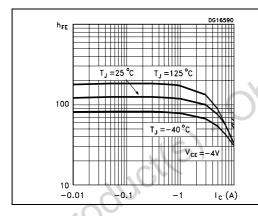


Figure 4. DC current gain

Figure 5. Collector-emitter saturation voltage



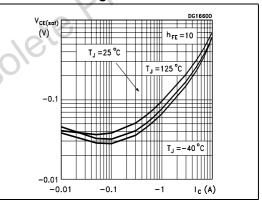
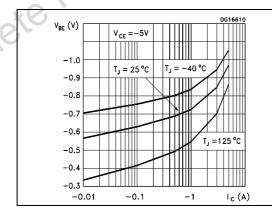
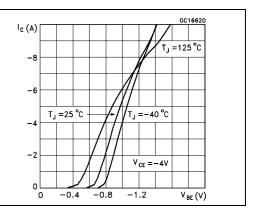


Figure 6. Base-emitter voltage

Figure 7. Base-emitter voltage

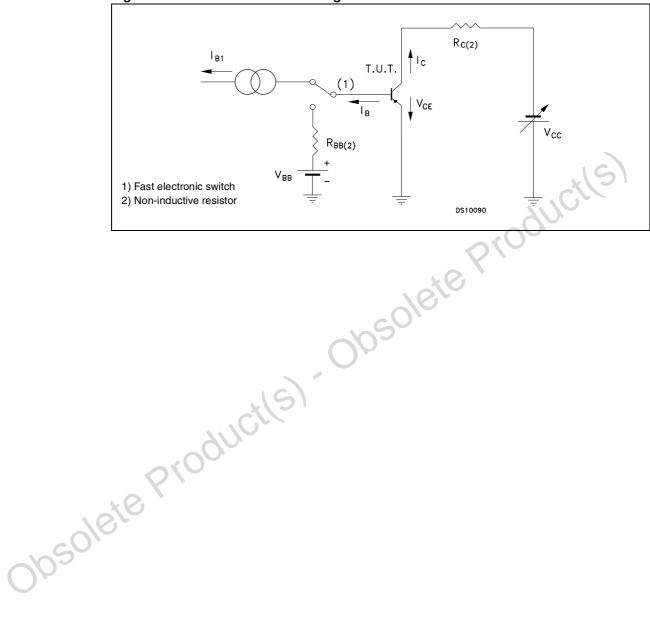




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### 2.2 Test circuit

Figure 8. Resistive load switching test circuit



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# 3 Package mechanical data

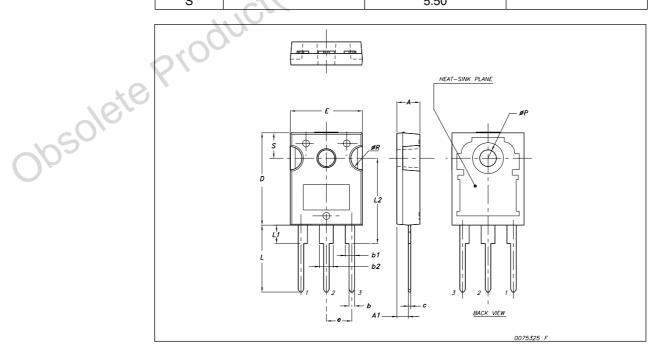
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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#### **TO-247 Mechanical data**

Dim.	mm.					
	Min.	Тур	Max.			
Α	4.85		5.15			
A1	2.20		2.60			
b	1.0		1.40			
b1	2.0		2.40			
b2	3.0		3.40			
С	0.40		0.80			
D	19.85		20.15			
E	15.45	40,	15.75			
е		5.45				
L	14.20		14.80			
L1	3.70	100	4.30			
L2		18.50				
øΡ	3.55		3.65			
øR	4.50		5.50			
S		5.50				



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Revision history 2STW1695

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes
23-Oct-2006	1	Initial release
23-Sep-2007	2	Added figures 2, 3, 4, 5, 6, 7.
20-Feb-2007	3	Document status promoted from preliminary data to datasheet.
06-Oct-2008	4	Content reworked to improve readability, no technical changes.
ie Produ	cils	Document status promoted from preliminary data to datasheet.  Content reworked to improve readability, no technical changes.

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